

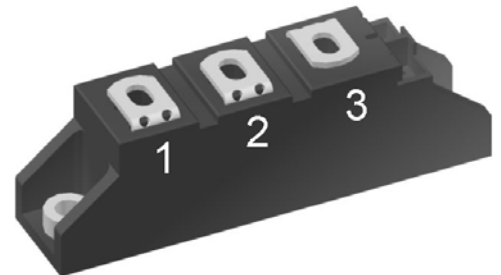
# Standard Rectifier Module

$$\begin{aligned} V_{RRM} &= 2 \times 800 \text{ V} \\ I_{FAV} &= 59 \text{ A} \\ V_F &= 1.26 \text{ V} \end{aligned}$$

Phase leg

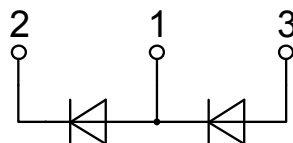
Part number

**MDD44-08N1B**



Backside: isolated

 E72873



## Features / Advantages:

- Package with DCB ceramic
- Improved temperature and power cycling
- Planar passivated chips
- Very low forward voltage drop
- Very low leakage current

## Applications:

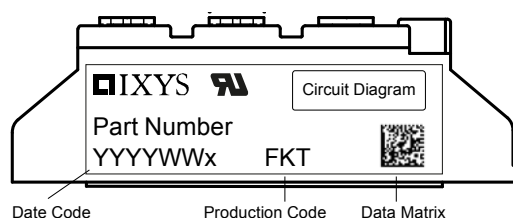
- Diode for main rectification
- For single and three phase bridge configurations
- Supplies for DC power equipment
- Input rectifiers for PWM inverter
- Battery DC power supplies
- Field supply for DC motors

## Package: TO-240AA

- Isolation Voltage: 3600V~
- Industry standard outline
- RoHS compliant
- Soldering pins for PCB mounting
- Base plate: DCB ceramic
- Reduced weight
- Advanced power cycling

| Rectifier    |                                              |                                         |                                | Ratings |      |      |                   |
|--------------|----------------------------------------------|-----------------------------------------|--------------------------------|---------|------|------|-------------------|
| Symbol       | Definition                                   | Conditions                              |                                | min.    | typ. | max. | Unit              |
| $V_{RSM}$    | max. non-repetitive reverse blocking voltage | $T_{VJ} = 25^{\circ}\text{C}$           |                                |         |      | 900  | V                 |
| $V_{RRM}$    | max. repetitive reverse blocking voltage     | $T_{VJ} = 25^{\circ}\text{C}$           |                                |         |      | 800  | V                 |
| $I_R$        | reverse current                              | $V_R = 800\text{ V}$                    | $T_{VJ} = 25^{\circ}\text{C}$  |         |      | 100  | $\mu\text{A}$     |
|              |                                              | $V_R = 800\text{ V}$                    | $T_{VJ} = 150^{\circ}\text{C}$ |         |      | 10   | mA                |
| $V_F$        | forward voltage drop                         | $I_F = 100\text{ A}$                    | $T_{VJ} = 25^{\circ}\text{C}$  |         |      | 1.30 | V                 |
|              |                                              | $I_F = 200\text{ A}$                    |                                |         |      | 1.60 | V                 |
|              |                                              | $I_F = 100\text{ A}$                    | $T_{VJ} = 125^{\circ}\text{C}$ |         |      | 1.26 | V                 |
|              |                                              | $I_F = 200\text{ A}$                    |                                |         |      | 1.67 | V                 |
| $I_{FAV}$    | average forward current                      | $T_C = 100^{\circ}\text{C}$             | $T_{VJ} = 150^{\circ}\text{C}$ |         |      | 59   | A                 |
| $I_{F(RMS)}$ | RMS forward current                          | 180° sine                               |                                |         |      | 100  | A                 |
| $V_{FO}$     | threshold voltage                            | } for power loss calculation only       | $T_{VJ} = 150^{\circ}\text{C}$ |         |      | 0.80 | V                 |
| $r_F$        | slope resistance                             |                                         |                                |         |      | 4.3  | m $\Omega$        |
| $R_{thJC}$   | thermal resistance junction to case          |                                         |                                |         |      | 0.59 | K/W               |
| $R_{thCH}$   | thermal resistance case to heatsink          |                                         |                                |         | 0.20 |      | K/W               |
| $P_{tot}$    | total power dissipation                      |                                         | $T_C = 25^{\circ}\text{C}$     |         |      | 212  | W                 |
| $I_{FSM}$    | max. forward surge current                   | $t = 10\text{ ms; (50 Hz), sine}$       | $T_{VJ} = 45^{\circ}\text{C}$  |         |      | 1.15 | kA                |
|              |                                              | $t = 8,3\text{ ms; (60 Hz), sine}$      | $V_R = 0\text{ V}$             |         |      | 1.24 | kA                |
|              |                                              | $t = 10\text{ ms; (50 Hz), sine}$       | $T_{VJ} = 150^{\circ}\text{C}$ |         |      | 980  | A                 |
|              |                                              | $t = 8,3\text{ ms; (60 Hz), sine}$      | $V_R = 0\text{ V}$             |         |      | 1.06 | kA                |
| $I^2t$       | value for fusing                             | $t = 10\text{ ms; (50 Hz), sine}$       | $T_{VJ} = 45^{\circ}\text{C}$  |         |      | 6.62 | kA <sup>2</sup> s |
|              |                                              | $t = 8,3\text{ ms; (60 Hz), sine}$      | $V_R = 0\text{ V}$             |         |      | 6.40 | kA <sup>2</sup> s |
|              |                                              | $t = 10\text{ ms; (50 Hz), sine}$       | $T_{VJ} = 150^{\circ}\text{C}$ |         |      | 4.80 | kA <sup>2</sup> s |
|              |                                              | $t = 8,3\text{ ms; (60 Hz), sine}$      | $V_R = 0\text{ V}$             |         |      | 4.63 | kA <sup>2</sup> s |
| $C_J$        | junction capacitance                         | $V_R = 400\text{ V; } f = 1\text{ MHz}$ | $T_{VJ} = 25^{\circ}\text{C}$  |         | 27   |      | pF                |

| Package TO-240AA      |                                                              |                      |                                         | Ratings |      |      |      |   |
|-----------------------|--------------------------------------------------------------|----------------------|-----------------------------------------|---------|------|------|------|---|
| Symbol                | Definition                                                   | Conditions           |                                         | min.    | typ. | max. | Unit |   |
| I <sub>RMS</sub>      | RMS current                                                  | per terminal         |                                         |         |      | 200  | A    |   |
| T <sub>stg</sub>      | storage temperature                                          |                      |                                         | -40     |      | 125  | °C   |   |
| T <sub>VJ</sub>       | virtual junction temperature                                 |                      |                                         | -40     |      | 150  | °C   |   |
| Weight                |                                                              |                      |                                         |         | 90   |      | g    |   |
| M <sub>D</sub>        | mounting torque                                              |                      |                                         | 2.5     |      | 4    | Nm   |   |
| M <sub>T</sub>        | terminal torque                                              |                      |                                         | 2.5     |      | 4    | Nm   |   |
| d <sub>Spp/App</sub>  | creepage distance on surface   striking distance through air | terminal to terminal | 13.0                                    | 9.7     |      |      | mm   |   |
| d <sub>Spb/Appb</sub> |                                                              | terminal to backside | 16.0                                    | 16.0    |      |      | mm   |   |
| V <sub>ISOL</sub>     | isolation voltage                                            | t = 1 second         | 50/60 Hz, RMS; I <sub>ISOL</sub> ≤ 1 mA |         | 3600 |      |      | V |
|                       |                                                              | t = 1 minute         |                                         |         | 3000 |      |      | V |

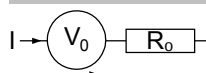


| Ordering | Part Number | Marking on Product | Delivery Mode | Quantity | Code No. |
|----------|-------------|--------------------|---------------|----------|----------|
| Standard | MDD44-08N1B | MDD44-08N1B        | Box           | 6        | 457973   |

### Equivalent Circuits for Simulation

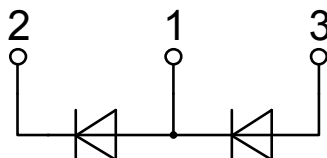
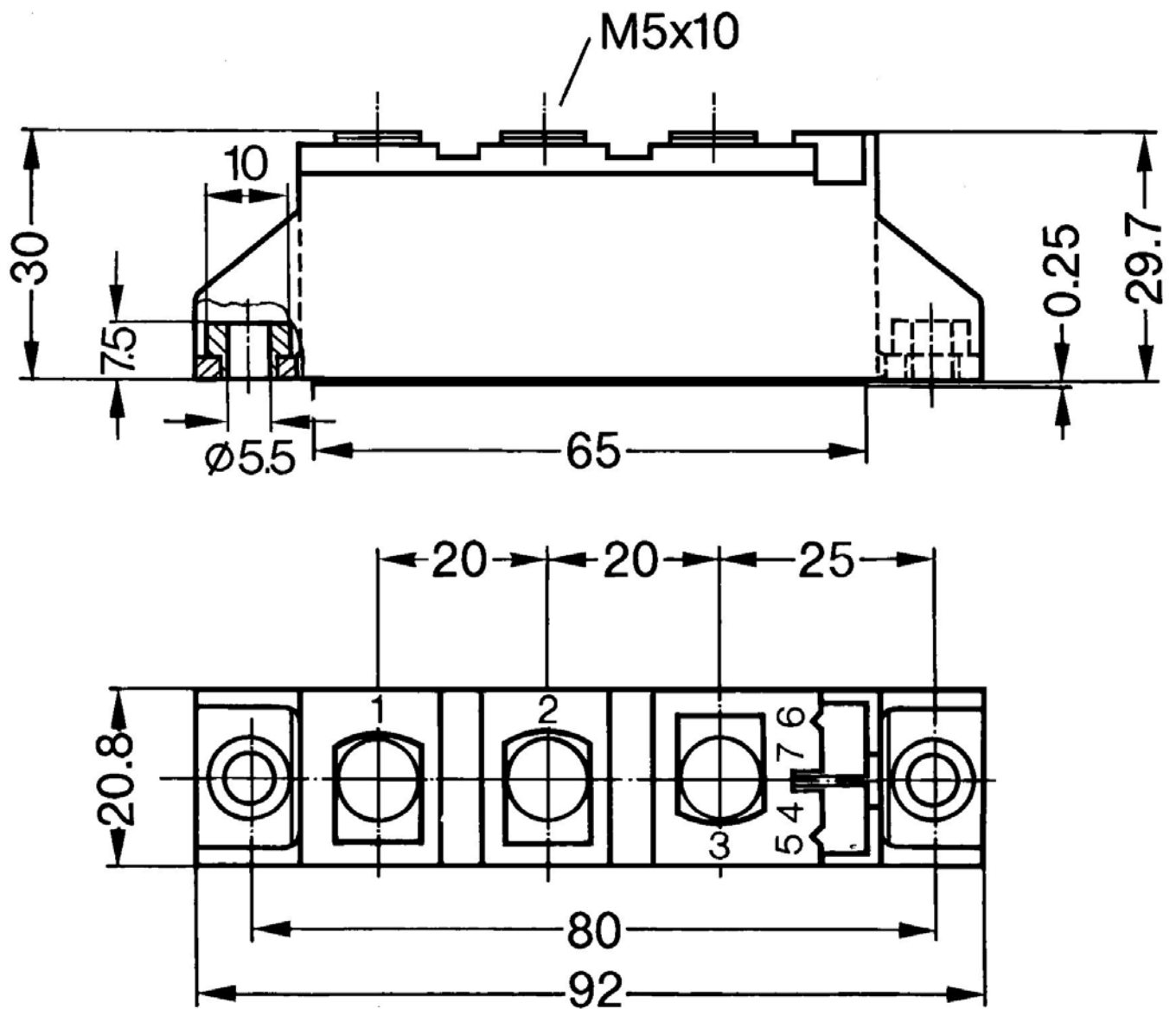
\* on die level

$T_{VJ} = 150^\circ\text{C}$



Rectifier

|             |                    |     |    |
|-------------|--------------------|-----|----|
| $V_{0\max}$ | threshold voltage  | 0.8 | V  |
| $R_{0\max}$ | slope resistance * | 3.1 | mΩ |



## Rectifier

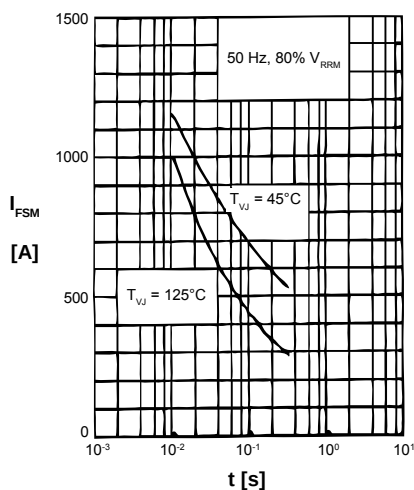


Fig. 1 Surge overload current  
 $I_{TSM}$ ,  $I_{FSM}$ : Crest value,  $t$ : duration

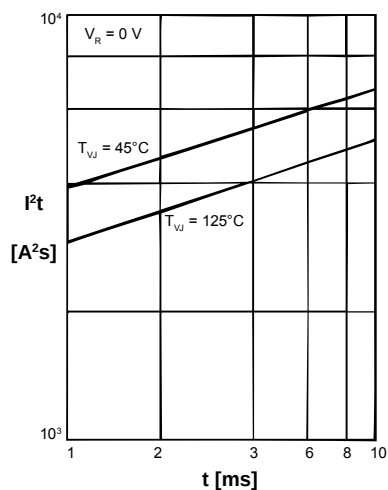


Fig. 2  $I^2t$  versus time (1-10 ms)

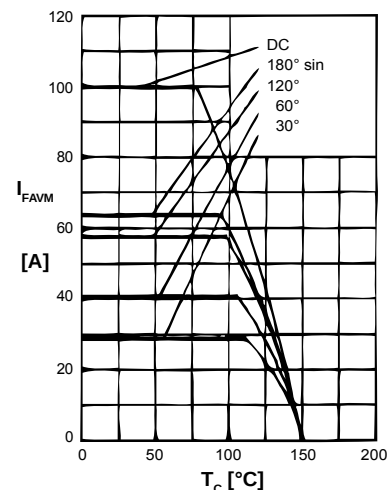


Fig. 3 Maximum forward current at case temperature

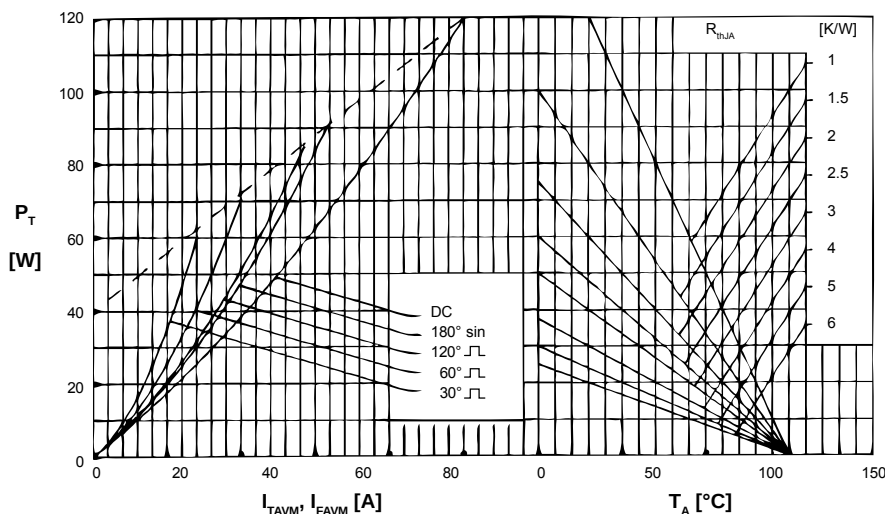


Fig. 4 Power dissipation vs. onstate current and ambient temperature (per diode)

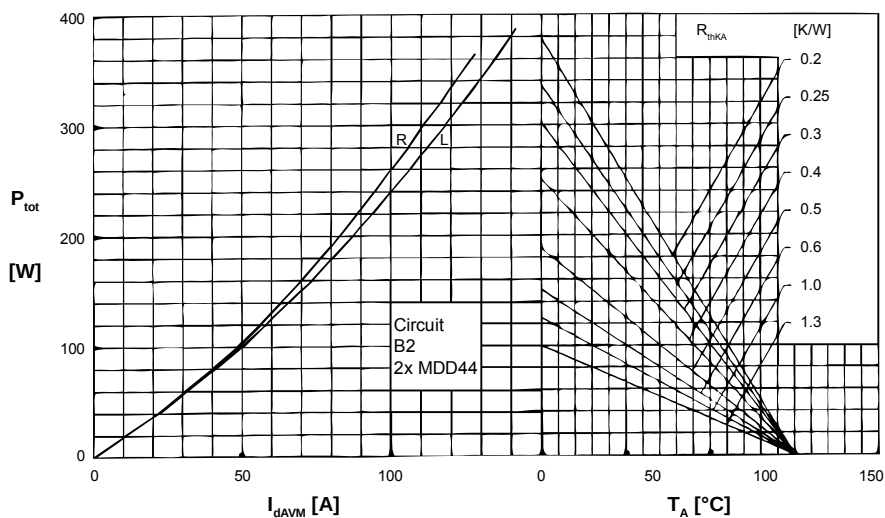


Fig. 6 Single phase rectifier bridge: Power dissipation versus direct output current and ambient temperature; R = resistive load, L = inductive load

## Rectifier

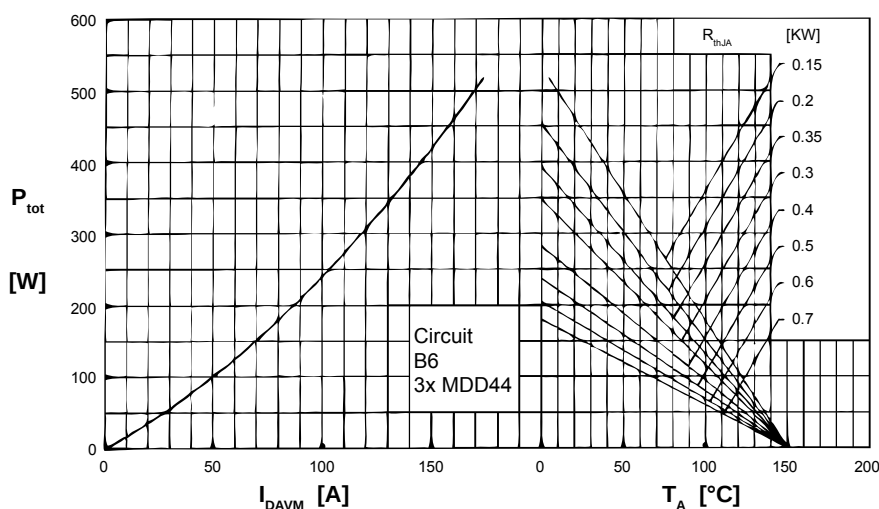


Fig. 6 Three phase rectifier bridge: Power dissipation versus direct output current and ambient temperature

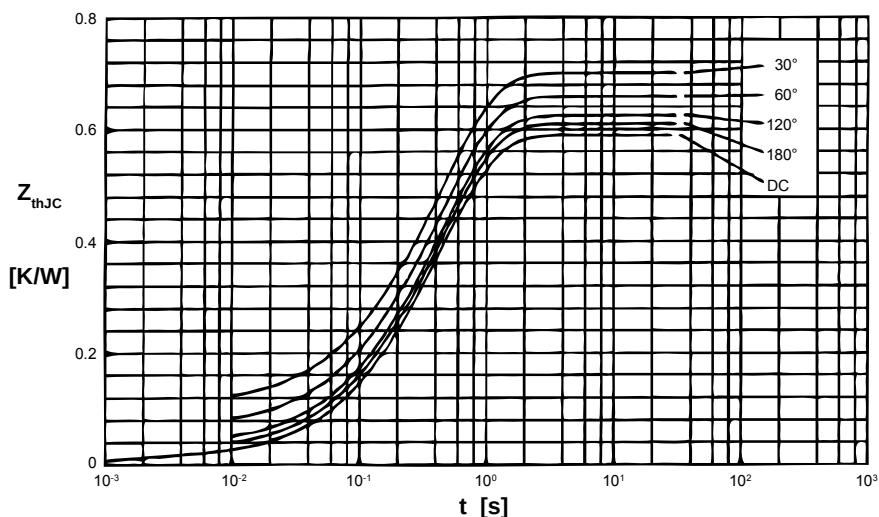


Fig. 7 Transient thermal impedance junction to case (per diode)

$R_{thJC}$  for various conduction angles d:

| d    | $R_{thJC}$ [K/W] |
|------|------------------|
| DC   | 0.59             |
| 180° | 0.61             |
| 120° | 0.63             |
| 60°  | 0.66             |
| 30°  | 0.70             |

Constants for  $Z_{thJC}$  calculation:

| i | $R_{thi}$ [K/W] | $t_i$ [s] |
|---|-----------------|-----------|
| 1 | 0.012           | 0.0012    |
| 2 | 0.045           | 0.0950    |
| 3 | 0.533           | 0.4550    |

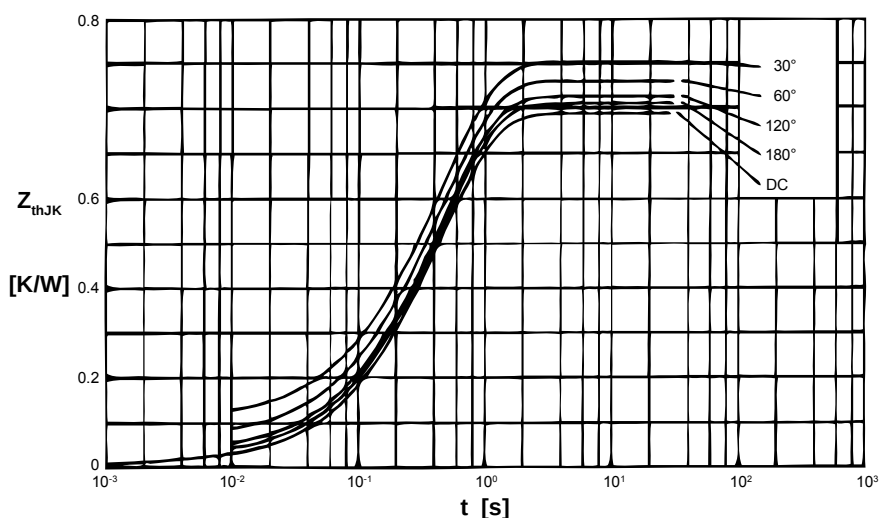


Fig. 8 Transient thermal impedance junction to heatsink (per thyristor)

$R_{thJK}$  for various conduction angles d:

| d    | $R_{thJK}$ [K/W] |
|------|------------------|
| DC   | 0.79             |
| 180° | 0.81             |
| 120° | 0.83             |
| 60°  | 0.86             |
| 30°  | 0.90             |

Constants for  $Z_{thJK}$  calculation:

| i | $R_{thi}$ [K/W] | $t_i$ [s] |
|---|-----------------|-----------|
| 1 | 0.012           | 0.0012    |
| 2 | 0.045           | 0.0950    |
| 3 | 0.533           | 0.4550    |
| 4 | 0.200           | 0.4950    |